



SDM1U100S1F

1A SCHOTTKY BARRIER RECTIFIER

Product Summary

V _{RRM} (V)	I _O (A)	V _F Max (V) @ +25°C	I _R Max (μA) @ +25°C
100	1	0.77	0.15

Description and Applications

The SDM1U100S1F is a single rectifier packaged in SOD123F (Standard). Offering low V_F , low power loss and high efficiency, this device is ideal for use in general rectification applications as a:

- Boost Diode
- Blocking Diode

Features and Benefits

- Guard Ring Die Construction for Transient Protection
- Low Power Loss, High Efficiency
- Interlocking Clip Design for High Surge Current Capacity
- Qualified to AEC-Q101 Standards
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Mechanical Data

- Case: SOD123F (Standard)
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish Annealed over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208 (@3)
- Polarity: Cathode Band
- Weight: 0.015 grams (Approximate)

SOD123F (Standard)



Top View

Ordering Information (Note 4)

Part Number	Case	Packaging
SDM1U100S1F-7	SOD123F (Standard)	3,000/Tape & Reel

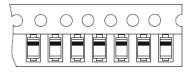
Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

Marking Information



<u>D</u>A = Product Type Marking Code
 YM = Date Code Marking
 Y = Year (ex.: E = 2017)
 M = Month (ex.: 9 = September)
 Bar Denotes Cathode Pin



Bar Denotes Cathode Pin

Date Code Key

Year	2013	2014	2015	2016	2017	2018	2019	2020
Code	Α	В	С	D	E	F	G	Н

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Maximum Ratings (@ $T_A = +25$ °C, unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derating current by 20%.

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _{RM}	100	V
Average Rectified Output Current	lo	1	Α
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load	I _{FSM}	50	Α

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Typical Thermal Resistance Junction to Case (Note 5) Typical Thermal Resistance Junction to Ambient (Note 5) Typical Thermal Resistance Junction to Case (Note 6) Typical Thermal Resistance Junction to Ambient (Note 6)	R _{OJC} R _{OJA} R _{OJC} R _{OJA}	50 120 40 100	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +175	°C

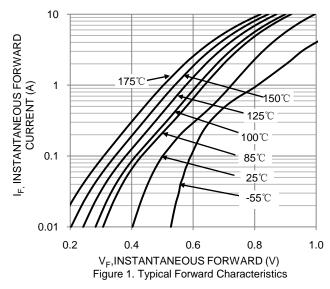
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

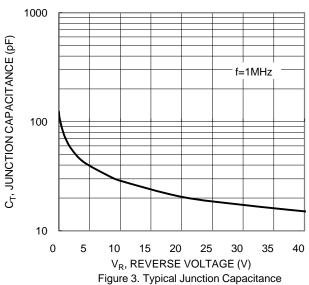
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 7)	V_R	100	_	_	V	$I_R = 1.0 \text{mA}$
Forward Voltage Drop	V _F	_	0.72 0.58	0.77 0.67	V	$I_F = 1A$, $T_J = +25$ °C $I_F = 1A$, $T_J = +125$ °C
Leakage Current (Note 7)	I _R	_	0.035 65	0.15 500	μΑ	$V_R = 100V, T_J = +25$ °C $V_R = 100V, T_J = +125$ °C
Total Capacitance	Ст	_	42		pF	$V_R = 4V, f = 1MHz$

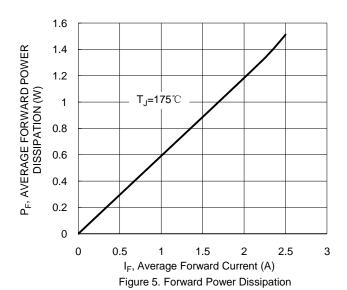
Notes:

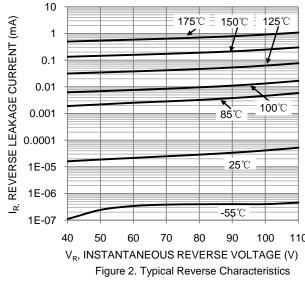
- 5. Device mounted on FR-4 substrate, 1"*1", 2oz, single-sided, PC boards with 0.1"*0.15" copper pad.
 6. Device mounted on FR-4 substrate, 0.4"*0.5", 2oz, single-sided, PC boards with 0.2"*0.25" copper pad.
 7. Short duration pulse test used to minimize self-heating effect.

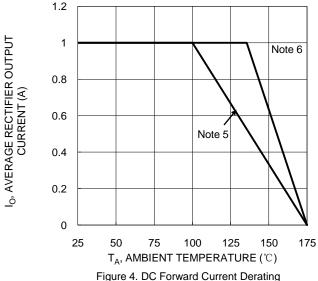










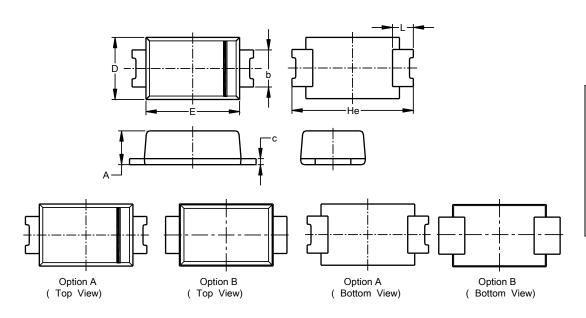




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOD123F (Standard)

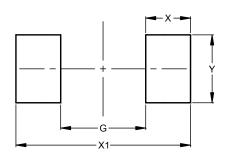


SOD123F (Standard)							
Dim	Min	Max	Тур				
Α	0.81	1.15	-				
b	0.80	1.35	-				
С	0.05	0.30	-				
D	1.70	1.90	1.80				
Е	2.60	2.80	2.70				
He	3.30	3.70	3.50				
L	0.35	0.85	-				
All Dimensions in mm							

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOD123F (Standard)



Dimensions	Value (in mm)
G	1.90
Х	1.00
X1	3.90
Υ	1.50



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